

**Silicon NPN Power Transistor**

**BDW93/A/B/C**

**DESCRIPTION**

- Collector Current  $-I_C = 12A$
- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 45V(\text{Min})$ - BDW93;  $60V(\text{Min})$ - BDW93A  
 $80V(\text{Min})$ - BDW93B;  $100V(\text{Min})$ - BDW93C
- Complement to Type BDW94/A/B/C

**APPLICATIONS**

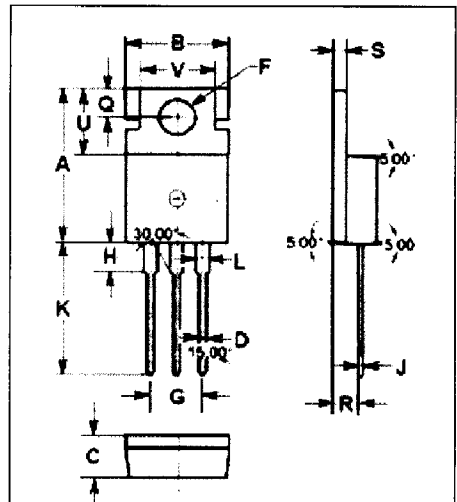
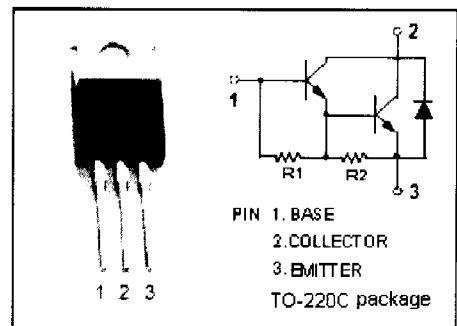
- Designed for hammer drivers, audio amplifier applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

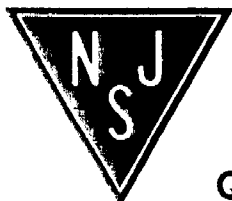
SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	BDW93	45
		BDW93A	60
		BDW93B	80
		BDW93C	100
$V_{CEO}$	Collector-Emitter Voltage	BDW93	45
		BDW93A	60
		BDW93B	80
		BDW93C	100
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	12	A
$I_{CM}$	Collector Current-Peak	15	A
$I_B$	Base Current	0.2	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	80	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-65~150	$^\circ\text{C}$

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th-j-c}$	Thermal Resistance, Junction to Case	1.5	$^\circ\text{C/W}$



DIM	mm	
	MIN	MAX
A	15.70	15.90
B	9.90	10.10
C	4.20	4.40
D	0.70	0.90
F	3.40	3.60
G	4.98	5.18
H	2.70	2.90
J	0.44	0.46
K	13.20	13.40
L	1.10	1.30
Q	2.70	2.90
R	2.50	2.70
S	1.29	1.31
U	6.45	6.65
V	8.66	8.86



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# BDW93/A/B/C

## ELECTRICAL CHARACTERISTICS

$T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	BDW93	100mA; $I_B=0$			V
		BDW93A				
		BDW93B				
		BDW93C				
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=5A; I_B=20mA$			2.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=10A; I_B=0.1A$			3.0	V
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C=5A; I_B=20mA$			2.5	V
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C=10A; I_B=0.1A$			4.0	V
$I_{CBO}$	Collector Cutoff Current	BDW93			0.1	mA
		BDW93A				
		BDW93B				
		BDW93C				
$I_{CEO}$	Collector Cutoff Current	BDW93			1.0	mA
		BDW93A				
		BDW93B				
		BDW93C				
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}=5V; I_C=0$			2.0	mA
$h_{FE-1}$	DC Current Gain	$I_C=3A; V_{CE}=3V$	1000			
$h_{FE-2}$	DC Current Gain	$I_C=5A; V_{CE}=3V$	750		20000	
$h_{FE-3}$	DC Current Gain	$I_C=10A; V_{CE}=3V$	100			
$V_{ECF-1}$	C-E Diode Forward Voltage	$I_F=5A$			2.0	V
$V_{ECF-2}$	C-E Diode Forward Voltage	$I_F=10A$			4.0	V